# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

## 2W005 THRU 2W10

SINGLE PHASE SILICON BRIDGE RECTIFIER TECHNICAL SPECIFICATION

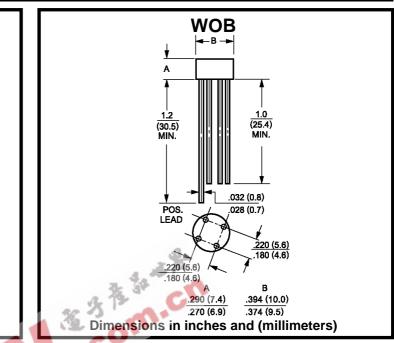
### VOLTAGE: 50 TO 1000V CURRENT: 2.0A

#### FEATURES

- Ideal for printed circuit board
- Surge overload rating: 60A peak
- High case dielectric strength
- High temperature soldering guaranteed: 250°C/10sec/0.375"(9.5mm) lead length at 5 lbs tension

#### **MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Polarity symbol marked on body
- Mounting position: Any



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	2W 005	2W 01	2W 02	2W 04	2W 06	2W 08	2W 10	UNITS
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current $(T_a=25^{\circ}C)$	I <sub>F(AV)</sub>	2.0							А
Peak Forward Surge Current (8.3ms single half sine-wave superimposed on rated load)	I <sub>FSM</sub>	60							А
Maximum Instantaneous Forward Voltage (at forward current 2.0A DC)	V <sub>F</sub>	1.0							V
Maximum DC Reverse Current $T_a=25^{\circ}C$ (at rated DC blocking voltage) $T_a=100^{\circ}C$		10.0 500							μΑ μΑ
Operating Temperature Range	TJ	-55 to +125							°C
Storage Temperature	T <sub>STG</sub>	-55 to +150							°C

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